



Pb Free Plating Product

DSEE30-04A thru DSEE30-24A

30.0 Ampere Heatsink Dual Tandem Structure In Series Ultra Fast Recovery Rectifiers

<p>Features</p> <ul style="list-style-type: none"> ThinkiSemi latest&matured process FRD/FRED Low forward voltage drop High current capability Low reverse leakage current High surge current capability <p>Application</p> <ul style="list-style-type: none"> Automotive Inverters and Solar Inverters Car Audio Amplifiers and Sound Device Systems Plating Power Supply, Motor Control, UPS and SMPS etc. <p>Mechanical Data</p> <ul style="list-style-type: none"> Case: Heat Sink TO-3PN/TO-3PB Outline Epoxy: UL 94V-0 rate flame retardant Terminals: Solderable per MIL-STD-202 method 208 Polarity: As marked on diode body Mounting position: Any Weight: 6.5 gram approximately 	<p>TO-3PN/TO-3PB</p> <p>Unit: inch(mm)</p> <p>Positive Common Cathode Prefix "DSEC" Negative Common Anode Prefix "DSEA" Doubler Tandem Polarity Prefix "DSED" Series Tandem Polarity Prefix "DSEE"</p>
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MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.
Single phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

PARAMETER	SYMBOL	DSEE30-04A	DSEE30-08A	DSEE30-12A	DSEE30-16A	DSEE30-20A	DSEE30-24A	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	200x2	400x2	600x2	800x2	1000x2	1200x2	V
Maximum RMS Voltage	VRMS	140x2	280x2	420x2	560x2	700x2	840x2	V
Maximum DC Blocking Voltage	VDC	200x2	400x2	600x2	800x2	1000x2	1200x2	V
Maximum Average Forward Rectified Current TC=125°C (Total Device 2x30.0A=60.0A)	IF(AV)	30.0						A
Peak Forward Surge Current, 8.3ms single Half sine-wave superimposed on rated load (JEDEC method)(Per Diode/Per Leg)	IFSM	300						A
Maximum Instantaneous Forward Voltage @30.0A(Per Diode/Per Leg)	VF (Typical)	0.85-0.95	1.00-1.25	1.25-1.50	1.50-1.70			V
Maximum DC Reverse Current @TJ=25°C At Rated DC Blocking Voltage @TJ=125°C	IR	1.0 100						µA µA
Maximum Reverse Recovery Time (Note1)	Trr	25-50			50-75			nS
Typical Junction Capacitance (Note 2)	CJ	150						pF
Typical Thermal Resistance (Note 3)	RθJC	0.75						°C/W
Operating Junction and Storage Temperature Range	TJ,TSTG	-55 to +175						°C

Note:(1)Reverse recovery test conditions IF = 0.5A, IR = 1.0A, Irr = 0.25A.
Note:(2)Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts DC.
Note:(3)Thermal Resistance junction to case.

FIG.1 - FORWARD CURRENT DERATING CURVE

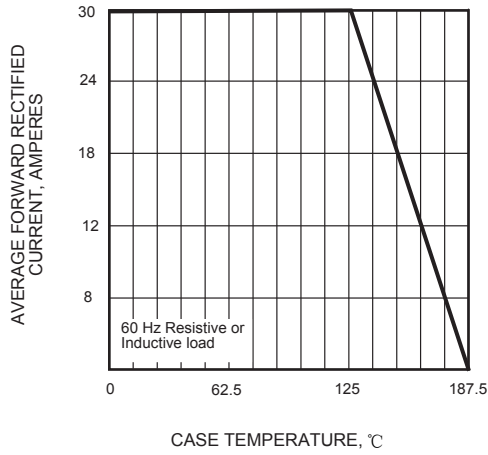


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

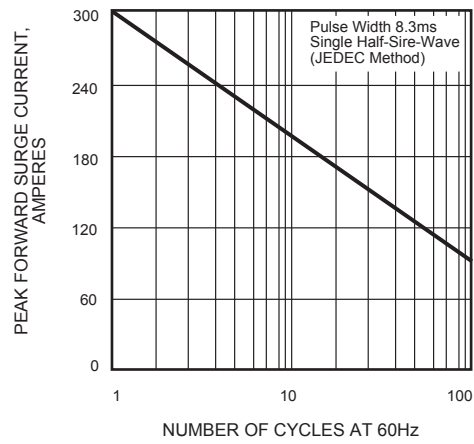


FIG.3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

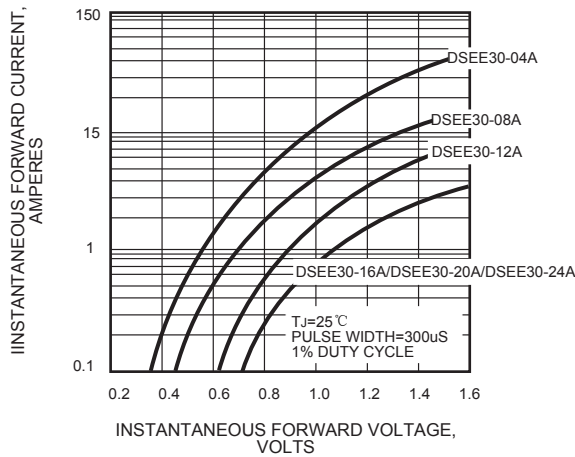


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

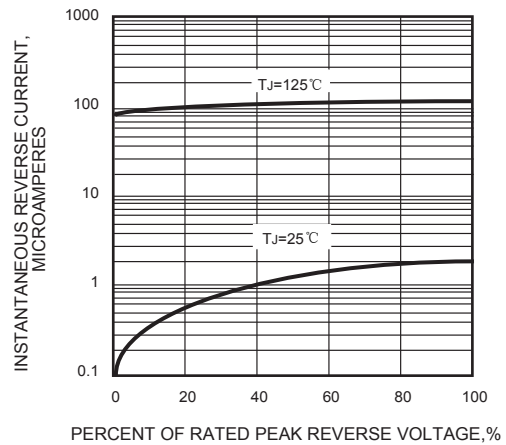


FIG.5 - TYPICAL JUNCTION CAPACITANCE

